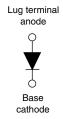


High Performance Schottky Rectifiers, 120 A



HALF-PAK (D-67)



PRIMARY CHARACTERISTICS			
I _{F(AV)} 120 A			
V_{R}	15 V		
Package	HALF-PAK (D-67)		
Circuit configuration	Single diode		

FEATURES

- 125 °C T_{.1} operation (V_R < 5 V)
- · Low forward voltage drop
- High frequency operation



- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified for industrial level
- UL approved file E222165
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-125NQ.. high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS A	
I _{F(AV)}	Rectangular waveform	120		
V _{RRM}		15	V	
I _{FSM}	t _p = 5 μs sine	10 800	Α	
V _F	120 A _{pk} , T _J = 125 °C	0.37	V	
T _J	Range	-55 to +125	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-125NQ015PbF	UNITS	
Maximum DC reverse voltage	V_{R}	15	V	
Maximum working peak reverse voltage	V_{RWM}	25] v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_C = 74 °C, rectangular waveform		120	
Maximum peak one cycle non-repetitive surge current See fig. 7		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	10 800	Α
	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	1700		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 5 A, L = 1 mH		12	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ sr Frequency limited by T_J maximum $V_A = 1.5$ x V_R typical		2	А



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	L TEST CONDITIONS VALUES		UNITS	
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	120 A	T _J = 25 °C	0.43	V
		240 A		0.58	
		120 A	T _J = 75 °C	0.37	
		240 A		0.52	
Maximum reverse leakage current per leg See fig. 2	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	40	· · · · · · · · · · · · · · · · · · ·
		T _J = 100 °C		2000	mA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		7700	рF
Typical series inductance	L _S	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V		V/µs	

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,~duty~cycle < 2~\%$

				1		
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperatur	e range	TJ		-55 to 125	°C	
Maximum storage temperatur	e range	T _{Stg}		-55 to 150		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	0.38	°C/W	
Typical thermal resistance, ca	se to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.05	0.05	
Approximate weight				30	g	
				1.06	oz.	
Mounting torque —	minimum			3 (26.5)		
	maximum		Non-lubricated threads	4 (35.4)	N · m	
Terminal torque	minimum			3.4 (30)	(lbf·in)	
	maximum			5 (44.2)		
Case style			HALF-PAK		(module	

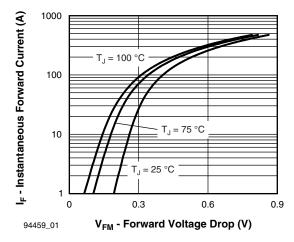


Fig. 1 - Maximum Forward Voltage Drop Characteristics

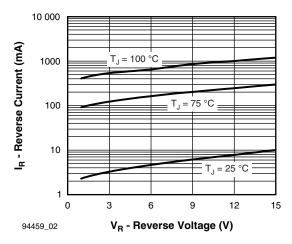


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

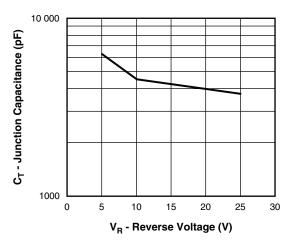


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

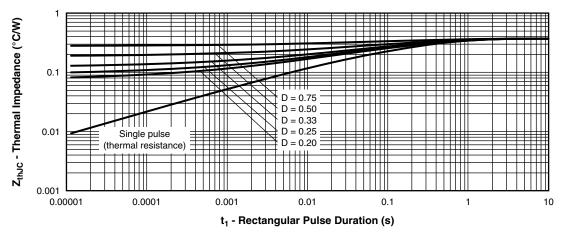


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

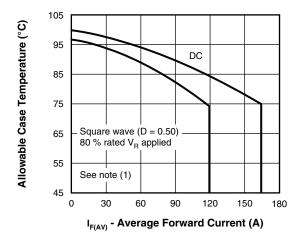


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

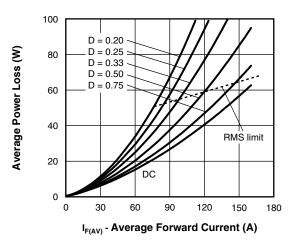
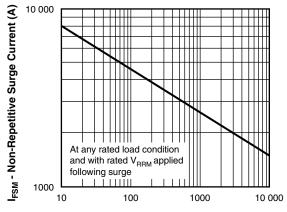


Fig. 6 - Forward Power Loss Characteristics



t_o - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

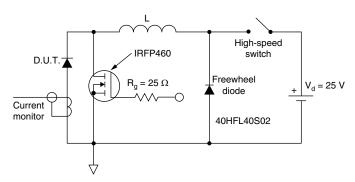


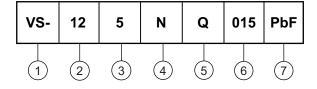
Fig. 8 - Unclamped Inductive Test Circuit

Note

 $\begin{array}{ll} \text{(1)} \ \ \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$

ORDERING INFORMATION TABLE

Device code



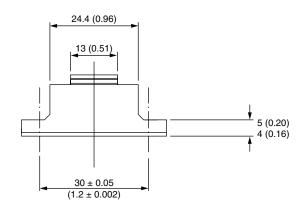
- Vishay Semiconductors product
- 2 Average current rating (x 10)
- 3 Product silicon identification
- 4 N = not isolated
- 5 Q = Schottky rectifier diode
- 6 Voltage rating (015 = 15 V)
- **7** Lead (Pb)-free

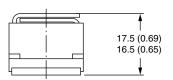
LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95020		

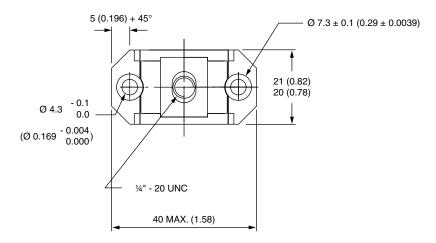


D-67 HALF-PAK

DIMENSIONS in millimeters (inches)









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